

One Watt High Current Transistors

NPN Silicon

MPSW01 MPSW01A*

*ON Semiconductor Preferred Device

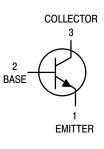
MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage MPSW01 MPSW01A	V _{CEO}	30 40	Vdc	
Collector–Base Voltage MPSW01 MPSW01A	V _{CBO}	40 50	Vdc	
Emitter-Base Voltage	V _{EBO}	5.0	Vdc	
Collector Current — Continuous	I _C	1000	mAdc	
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.0 8.0	Watts mW/°C	
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	2.5 20	Watts mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	50	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Breakdown Voltage ⁽¹⁾ (I _C = 10 mAdc, I _B = 0)	MPSW01 MPSW01A	V _{(BR)CEO}	30 40	_	Vdc
Collector–Base Breakdown Voltage ($I_C = 100 \mu Adc, I_E = 0$)	MPSW01 MPSW01A	V _{(BR)CBO}	40 50		Vdc
Emitter–Base Breakdown Voltage $(I_E = 100 \mu Adc, I_C = 0)$		V _{(BR)EBO}	5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPSW01 MPSW01A	I _{CBO}	_ _	0.1 0.1	μAdc
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)		I _{EBO}	_	0.1	μAdc

^{1.} Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

MPSW01 MPSW01A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

	,			
Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS ⁽¹⁾	1		•	
DC Current Gain $ \begin{aligned} &(I_C=10 \text{ mAdc}, V_{CE}=1.0 \text{ Vdc}) \\ &(I_C=100 \text{ mAdc}, V_{CE}=1.0 \text{ Vdc}) \\ &(I_C=1000 \text{ mAdc}, V_{CE}=1.0 \text{ Vdc}) \end{aligned} $	h _{FE}	55 60 50	_ _ _	_
Collector–Emitter Saturation Voltage ($I_C = 1000 \text{ mAdc}$, $I_B = 100 \text{ mAdc}$)	V _{CE(sat)}	_	0.5	Vdc
Base–Emitter On Voltage (I _C = 1000 mAdc, V _{CE} = 1.0 Vdc)	V _{BE(on)}	_	1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current–Gain — Bandwidth Product $(I_C = 50 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 20 \text{ MHz})$	f _T	50	_	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{obo}	_	20	pF

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

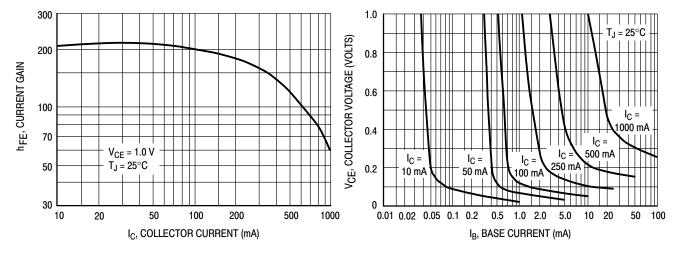


Figure 1. DC Current Gain

Figure 2. Collector Saturation Region

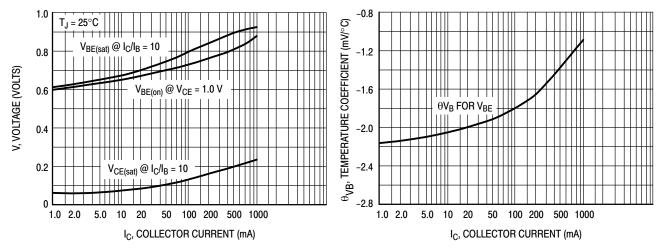


Figure 3. "ON" Voltages

Figure 4. Temperature Coefficient

MPSW01 MPSW01A

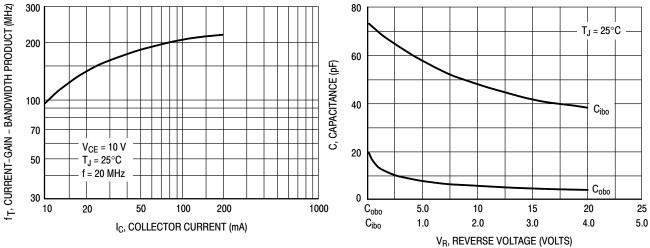


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

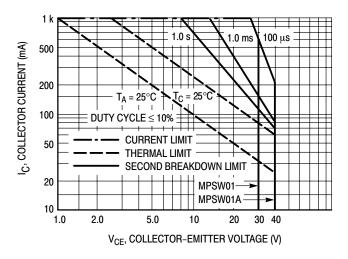
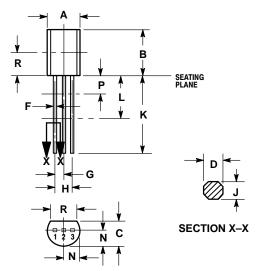


Figure 7. Active Region — Safe Operating Area

MPSW01 MPSW01A

PACKAGE DIMENSIONS

TO-92 (TO-226) **CASE 29-10 ISSUE AL**



1F 5 PIN 1. DRAIN

SOURCE

GATE

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.

 DIMENSION F APPLIES BETWEEN P AND L.
- DIMENSIONS D AND J APPLY BETWEEN L AND K
 MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.457	0.533
F	0.016	0.019	0.407	0.482
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	

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